

TLV2241, TLV2242, TLV2244 FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED - NOVEMBER 2000

- Micropower Operation . . . 1 μ A/Channel
- Rail-to-Rail Input/Output
- Gain Bandwidth Product . . . 5.5 kHz
- Supply Voltage Range . . . 2.5 V to 12 V
- Specified Temperature Range
 - $T_A = 0^\circ\text{C}$ to 70°C . . . Commercial Grade
 - $T_A = -40^\circ\text{C}$ to 125°C . . . Industrial Grade
- Ultrasmall Packaging
 - 5-Pin SOT-23 (TLV2241)
 - 8-Pin MSOP (TLV2242)
- Universal OpAmp EVM

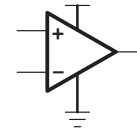
description

The TLV224x family of single-supply operational amplifiers offers very low supply current of only 1 μ A per channel.

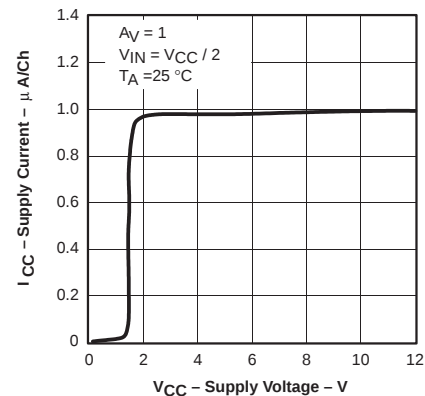
The low supply current is coupled with extremely low input bias currents enabling them to be used with mega- Ω resistors making them ideal for portable, long active life, applications. DC accuracy is ensured with a low typical offset voltage as low as 600 μ V, CMRR of 100 dB, and minimum open loop gain of 100 V/mV at 2.7 V.

The maximum recommended supply voltage is as high as 12 V and ensured operation down to 2.5 V, with electrical characteristics specified at 2.7 V, 5 V and 12 V. The 2.5-V operation makes it compatible with Li-Ion battery-powered systems and many micropower microcontrollers available today including TI's MSP430.

Operational Amplifier



SUPPLY CURRENT
vs
SUPPLY VOLTAGE



FAMILY PACKAGE TABLE

DEVICE	NO. OF Ch	PACKAGE TYPES					UNIVERSAL EVM
		PDIP	SOIC	SOT-23	TSSOP	MSOP	
TLV2241	1	8	8	5	—	—	Refer to the EVM Selection Guide (Lit# SLOU060)
TLV2242	2	8	8	—	—	8	
TLV2244	4	14	14	—	14	—	

SELECTION OF SINGLE SUPPLY OPERATIONAL AMPLIFIER PRODUCTS[†]

DEVICE	V _{DD} (V)	V _{IO} (mV)	BW (MHz)	SLEW RATE (V/ μ s)	I _{DD} (PER CHANNEL) (μ A)	RAIL-TO-RAIL
TLV240x [‡]	2.5–16	0.390	0.005	0.002	0.880	I/O
TLV224x	2.5–12	0.600	0.005	0.002	1	I/O
TLV2211	2.7–10	0.450	0.065	0.025	13	O
TLV245x	2.7–6	0.020	0.22	0.110	23	I/O
TLV225x	2.7–8	0.200	0.2	0.12	35	O

[†] All specifications are typical values measured at 5 V.

[‡] This device also offers 18-V reverse battery protection and 5-V over-the-rail operation on the inputs.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

Copyright © 2000, Texas Instruments Incorporated

TLV2241, TLV2242, TLV2244

FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT

OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED - NOVEMBER 2000

TLV2241 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES			
		SMALL OUTLINE† (D)	SOT-23‡ (DBV)	SYMBOLS	PLASTIC DIP (P)
0°C to 70°C	3000 μ V	TLV2241CD	—	—	—
–40°C to 125°C		TLV2241ID	TLV2241IDBV	VBEI	TLV2241IP

† This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2241CDR).

‡ This package is available in a 250 piece mini-reel. To order this package, add a T suffix to the part number (e.g., TLV2241IDBVT). This package is also available in a 3000 piece reel, add a R suffix to the part number (e.g., TLV2241IDBVR).

TLV2242 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES			
		SMALL OUTLINE† (D)	MSOP† (DGK)	SYMBOLS	PLASTIC DIP (P)
0°C to 70°C	3000 μ V	TLV2242CD	—	—	—
–40°C to 125°C		TLV2242ID	TLV2242IDGK	xxTIALE	TLV2242IP

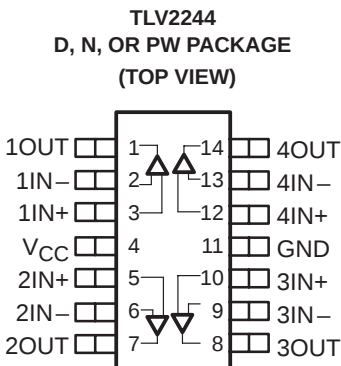
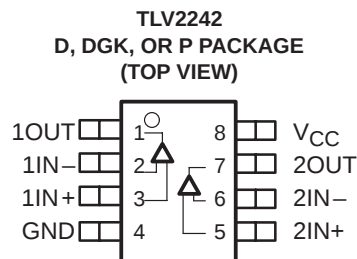
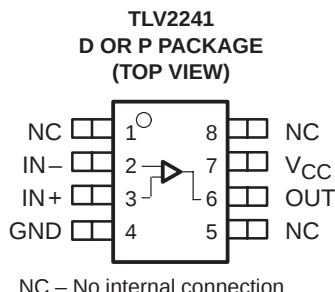
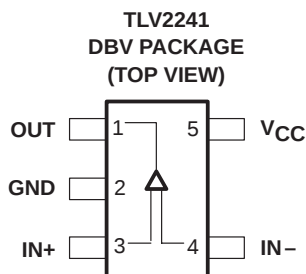
† This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2242CDR).

TLV2244 AVAILABLE OPTIONS

T _A	V _{IO} max AT 25°C	PACKAGED DEVICES		
		SMALL OUTLINE† (D)	PLASTIC DIP (N)	TSSOP (PW)
0°C to 70°C	3000 μ V	TLV2244CD	—	—
–40°C to 125°C		TLV2244ID	TLV2244IN	TLV2244IPW

† This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2244CDR).

TLV224x PACKAGE PINOUTS



TLV2241, TLV2242, TLV2244
FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT
OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED - NOVEMBER 2000

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{CC} (see Note 1)	16.5 V
Differential input voltage, V_{ID}	$\pm V_{CC}$
Input current, I_I (any input)	± 10 mA
Output current, I_O	± 10 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : C suffix	0°C to 70°C
I suffix	–40°C to 125°C
Maximum junction temperature, T_J	150°C
Storage temperature range, T_{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values, except differential voltages, are with respect to GND

DISSIPATION RATING TABLE

PACKAGE	Θ_{JC} (°C/W)	Θ_{JA} (°C/W)	$T_A \leq 25^\circ\text{C}$ POWER RATING	$T_A = 125^\circ\text{C}$ POWER RATING
D (8)	38.3	176	710 mW	142 mW
D (14)	26.9	122.6	1022 mW	204.4 mW
DBV (5)	55	324.1	385 mW	77.1 mW
DGK (8)	54.2	259.9	481 mW	96.2 mW
N (14)	32	78	1600 mW	320.5 mW
P (8)	41	104	1200 mW	240.4 mW
PW (14)	29.3	173.6	720 mW	144 mW

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V_{CC}	Single supply	2.5	12	V
	Split supply	± 1.25	± 6	
Common-mode input voltage range, V_{ICR}		0	V_{CC}	V
Operating free-air temperature, T_A	C-suffix	0	70	°C
	I-suffix	–40	125	

TLV2241, TLV2242, TLV2244

FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT

OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED - NOVEMBER 2000

electrical characteristics at recommended operating conditions, $V_{CC} = 2.7, 5 \text{ V}$, and 12 V (unless otherwise noted)[†]

dc performance

PARAMETER	TEST CONDITIONS	T_A [†]	MIN	TYP	MAX	UNIT
V_{IO} Input offset voltage	$V_O = V_{CC}/2 \text{ V}$, $V_{IC} = V_{CC}/2 \text{ V}$, $R_S = 50 \Omega$	25°C		600	3000	μV
		Full range			4500	
αV_{IO} Offset voltage drift		25°C		3		$\mu\text{V}/^\circ\text{C}$
CMRR Common-mode rejection ratio	$V_{IC} = 0 \text{ to } V_{CC}$, $R_S = 50 \Omega$	$V_{CC} = 2.7 \text{ V}$				dB
		25°C		55	100	
		Full range		50		
		$V_{CC} = 5 \text{ V}$				
		25°C		60	100	
		Full range		53		
		$V_{CC} = 12 \text{ V}$				
		25°C		60	100	
		Full range		55		
AVD Large-signal differential voltage amplification	$V_{CC} = 2.7 \text{ V}$, $V_{O(pp)} = 1 \text{ V}$, $R_L = 500 \text{ k}\Omega$	25°C		100	400	V/mV
		Full range		30		
		$V_{CC} = 5 \text{ V}$, $V_{O(pp)} = 3 \text{ V}$, $R_L = 500 \text{ k}\Omega$				
		25°C		250	1000	
		Full range		100		
		$V_{CC} = 12 \text{ V}$, $V_{O(pp)} = 6 \text{ V}$, $R_L = 500 \text{ k}\Omega$				
		25°C		700	1500	
		Full range		120		

[†] Full range is 0°C to 70°C for the C suffix and –40°C to 125°C for the I suffix. If not specified, full range is –40°C to 125°C.

input characteristics

PARAMETER	TEST CONDITIONS	T_A [†]	MIN	TYP	MAX	UNIT
I_{IO} Input offset current	$V_O = V_{CC}/2 \text{ V}$, $V_{IC} = V_{CC}/2 \text{ V}$, $R_S = 50 \Omega$	25°C		25	250	pA
		TLV224xC			300	
		TLV224xI			400	
I_{IB} Input bias current	$V_O = V_{CC}/2 \text{ V}$, $V_{IC} = V_{CC}/2 \text{ V}$, $R_S = 50 \Omega$	25°C		100	500	pA
		TLV224xC			550	
		TLV224xI			1000	
$r_{i(d)}$ Differential input resistance		25°C		300		$\text{M}\Omega$
$C_{i(c)}$ Common-mode input capacitance	$f = 100 \text{ kHz}$	25°C		3		pF

[†] Full range is 0°C to 70°C for the C suffix and –40°C to 125°C for the I suffix. If not specified, full range is –40°C to 125°C.

[‡] Specifications at 5 V are ensured by design and device testing at 2.7 V and 12 V.



TLV2241, TLV2242, TLV2244
FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT
OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED - NOVEMBER 2000

electrical characteristics at recommended operating conditions, $V_{CC} = 2.7, 5 \text{ V}$, and 12 V (unless otherwise noted)[†] (continued)

output characteristics

PARAMETER		TEST CONDITIONS		T _A [†]	MIN	TYP	MAX	UNIT
V _{OH}	High-level output voltage	V _{IC} = V _{CC} /2, I _{OH} = −2 μA	V _{CC} = 2.7 V	25°C	2.65	2.68		V
				Full range	2.63			
			V _{CC} = 5 V	25°C	4.95	4.98		
				Full range	4.93			
			V _{CC} = 12 V	25°C	11.95	11.98		
				Full range	11.93			
		V _{IC} = V _{CC} /2, I _{OH} = −50 μA	V _{CC} = 2.7 V	25°C	2.62	2.65		
				Full range	2.6			
			V _{CC} = 5 V	25°C	4.92	4.95		
				Full range	4.9			
			V _{CC} = 12 V	25°C	11.92	11.95		
				Full range	11.9			
V _{OL}	Low-level output voltage	V _{IC} = V _{CC} /2, I _{OL} = 2 μA		25°C		90	150	mV
				Full range			180	
		V _{IC} = V _{CC} /2, I _{OL} = 50 μA		25°C		180	230	
				Full range			260	
I _O	Output current	V _O = 0.5 V from rail		25°C		±200		μA

[†] Full range is 0°C to 70°C for the C suffix and –40°C to 125°C for the I suffix. If not specified, full range is –40°C to 125°C.

power supply

PARAMETER	TEST CONDITIONS		T_A [†]	MIN	TYP	MAX	UNIT
I_{CC} Supply current (per channel)	$V_O = V_{CC}/2$	$V_{CC} = 2.7 \text{ V}$ or 5 V	25°C		980	1200	nA
			Full range			1500	
		$V_{CC} = 12 \text{ V}$	25°C		1000	1250	
			Full range			1550	
PSRR Power supply rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$)	$V_{CC} = 2.7$ to 5 V , $V_{IC} = V_{CC}/2 \text{ V}$, No load,	TLV224xC	25°C	70	100		dB
			Full range	65			dB
		TLV224xI	25°C	70	100		dB
			Full range	70			dB
	$V_{CC} = 5$ to 12 V , $V_{IC} = V_{CC}/2 \text{ V}$, No load		25°C	70	100		dB
			Full range	70			dB

[†] Full range is 0°C to 70°C for the C suffix and –40°C to 125°C for the I suffix. If not specified, full range is –40°C to 125°C.

[‡] Specifications at 5 V are ensured by design and device testing at 2.7 V and 12 V.



TLV2241, TLV2242, TLV2244
FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT
OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED - NOVEMBER 2000

electrical characteristics at recommended operating conditions, $V_{CC} = 2.7, 5 \text{ V}$, and 12 V (unless otherwise noted)[‡] (continued)

dynamic performance

PARAMETER		TEST CONDITIONS		T_A	MIN	TYP	MAX	UNIT
UGBW	Unity gain bandwidth	$R_L = 500 \text{ k}\Omega$,	$C_L = 100 \text{ pF}$	25°C		5.5		kHz
SR	Slew rate at unity gain	$V_{O(pp)} = 0.8 \text{ V}$, $R_L = 500 \text{ k}\Omega$,	$C_L = 100 \text{ pF}$	25°C		2		V/ms
ϕM	Phase margin	$R_L = 500 \text{ k}\Omega$, $C_L = 100 \text{ pF}$		25°C		60		
	Gain margin					15		dB
t_s	Settling time	$V_{CC} = 2.7 \text{ or } 5 \text{ V}$, $V_{(STEP)PP} = 1 \text{ V}$, $C_L = 100 \text{ pF}$, $A_V = -1$, $R_L = 100 \text{ k}\Omega$	0.1%	25°C		1.84		ms
		$V_{CC} = 12 \text{ V}$, $V_{(STEP)PP} = 1 \text{ V}$, $C_L = 100 \text{ pF}$, $A_V = -1$, $R_L = 100 \text{ k}\Omega$	0.1%			6.1		
		$V_{CC} = 12 \text{ V}$, $V_{(STEP)PP} = 1 \text{ V}$, $C_L = 100 \text{ pF}$, $A_V = -1$, $R_L = 100 \text{ k}\Omega$	0.01%			32		

noise/distortion performance

PARAMETER		TEST CONDITIONS	T_A	MIN	TYP	MAX	UNIT
V_n	Equivalent input noise voltage	$f = 10 \text{ Hz}$	25°C		800		$\text{nV}/\sqrt{\text{Hz}}$
		$f = 100 \text{ Hz}$			500		
I_n	Equivalent input noise current	$f = 100 \text{ Hz}$			8		$\text{fA}/\sqrt{\text{Hz}}$

[‡] Specifications at 5 V are ensured by design and device testing at 2.7 V and 12 V.

TLV2241, TLV2242, TLV2244
FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT
OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED - NOVEMBER 2000

TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	vs Common-mode input voltage	1, 2, 3
I_{IB}	Input bias current	vs Free-air temperature	4, 6, 8
		vs Common-mode input voltage	5, 7, 9
I_{IO}	Input offset current	vs Free-air temperature	4, 6, 8
		vs Common-mode input voltage	5, 7, 9
CMRR	Common-mode rejection ratio	vs Frequency	10
V_{OH}	High-level output voltage	vs High-level output current	11, 13, 15
V_{OL}	Low-level output voltage	vs Low-level output current	12, 14, 16
$V_{O(PP)}$	Output voltage peak-to-peak	vs Frequency	17
Z_o	Output impedance	vs Frequency	18
I_{CC}	Supply current	vs Supply voltage	19
PSRR	Power supply rejection ratio	vs Frequency	20
A_{VD}	Differential voltage gain	vs Frequency	21
	Phase	vs Frequency	21
	Gain-bandwidth product	vs Supply voltage	22
SR	Slew rate	vs Free-air temperature	23
ϕ_m	Phase margin	vs Capacitive load	24
	Gain margin	vs Capacitive load	25
	Voltage noise over a 10 Second Period		26
	Large-signal voltage follower		27, 28, 29
	Small-signal voltage follower		30
	Large-signal inverting pulse response		31, 32, 33
	Small-signal inverting pulse response		34
	Crosstalk	vs Frequency	35

TLV2241, TLV2242, TLV2244

FAMILY OF 1- μ A/ch RAIL-TO-RAIL INPUT/OUTPUT

OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED – NOVEMBER 2000

TYPICAL CHARACTERISTICS

INPUT OFFSET VOLTAGE
vs
COMMON-MODE INPUT
VOLTAGE

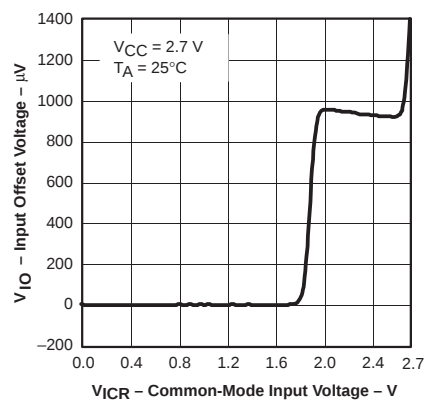


Figure 1

INPUT OFFSET VOLTAGE
vs
COMMON-MODE INPUT
VOLTAGE

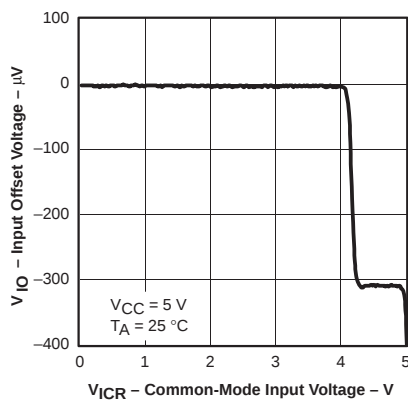


Figure 2

INPUT OFFSET VOLTAGE
vs
COMMON-MODE INPUT
VOLTAGE

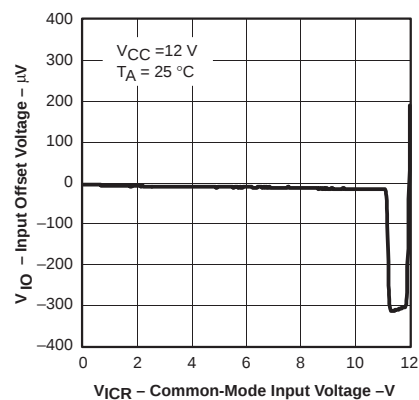


Figure 3

INPUT BIAS / OFFSET CURRENT
vs
FREE-AIR TEMPERATURE

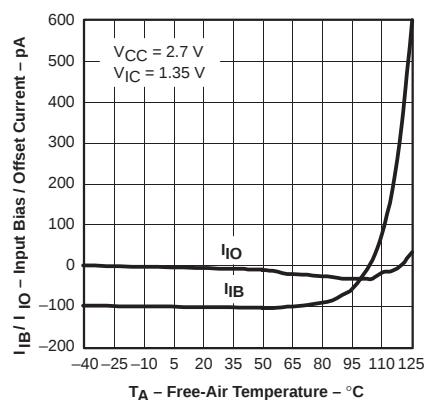


Figure 4

INPUT BIAS / OFFSET CURRENT
vs
COMMON MODE INPUT
VOLTAGE

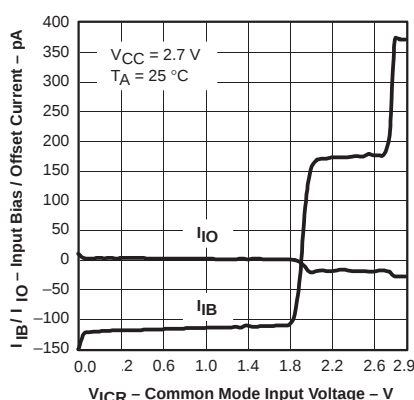


Figure 5

INPUT BIAS / OFFSET CURRENT
vs
FREE-AIR TEMPERATURE

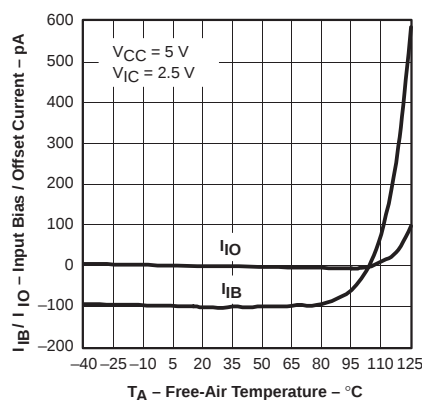


Figure 6

INPUT BIAS / OFFSET CURRENT
vs
COMMON-MODE INPUT
VOLTAGE

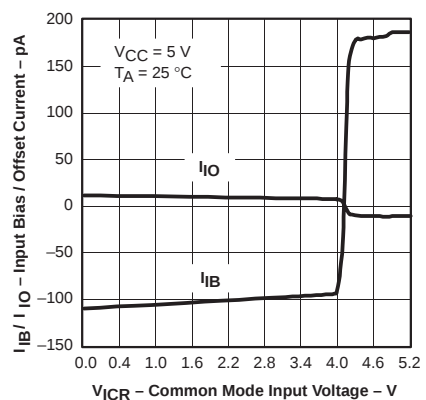


Figure 7

INPUT BIAS / OFFSET CURRENT
vs
FREE-AIR TEMPERATURE

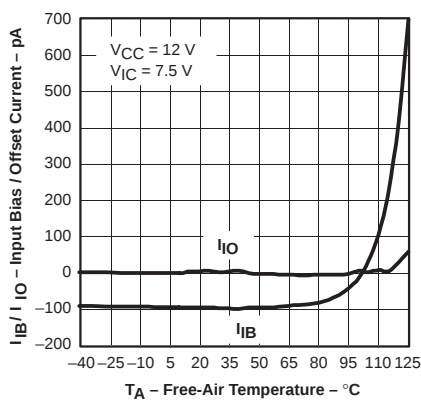


Figure 8

INPUT BIAS / OFFSET CURRENT
vs
COMMON-MODE INPUT
VOLTAGE

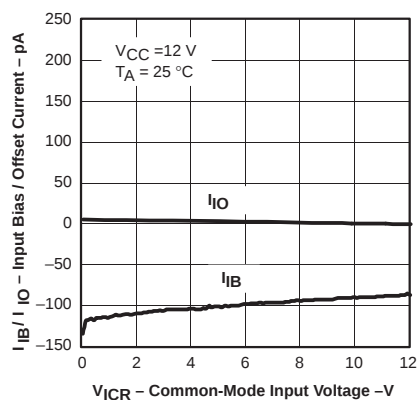


Figure 9



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

TLV2241, TLV2242, TLV2244

FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED – NOVEMBER 2000

TYPICAL CHARACTERISTICS

**COMMON-MODE REJECTION RATIO
VS
FREQUENCY**

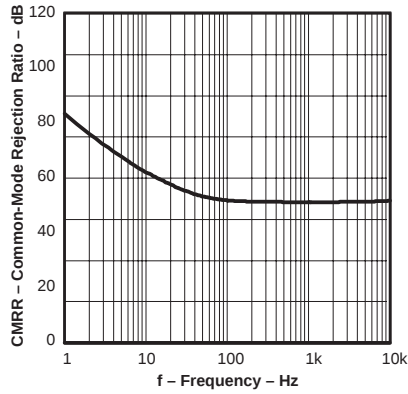


Figure 10

**HIGH-LEVEL OUTPUT VOLTAGE
VS
HIGH-LEVEL OUTPUT CURRENT**

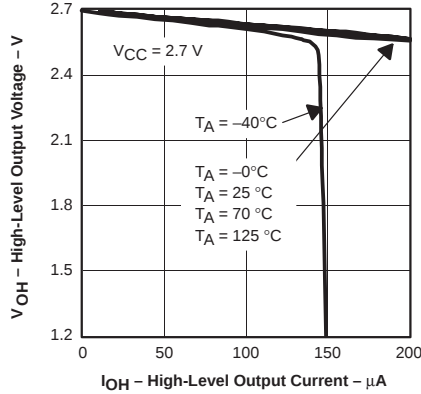


Figure 11

**LOW-LEVEL OUTPUT VOLTAGE
VS
LOW-LEVEL OUTPUT CURRENT**

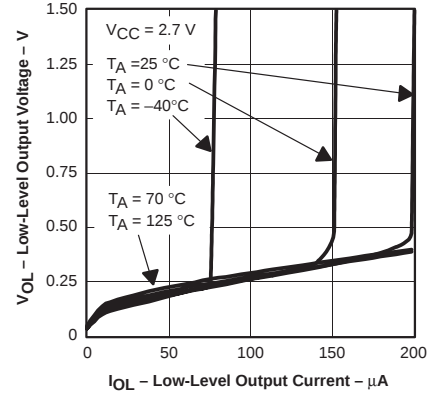


Figure 12

**HIGH-LEVEL OUTPUT VOLTAGE
VS
HIGH-LEVEL OUTPUT CURRENT**

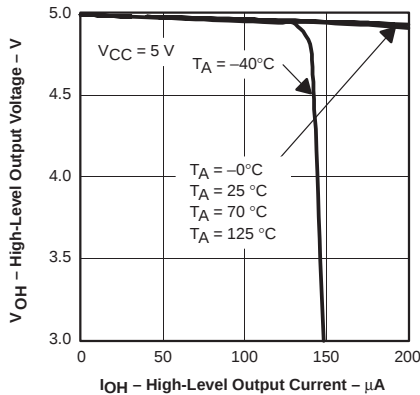


Figure 13

**LOW-LEVEL OUTPUT VOLTAGE
VS
LOW-LEVEL OUTPUT CURRENT**

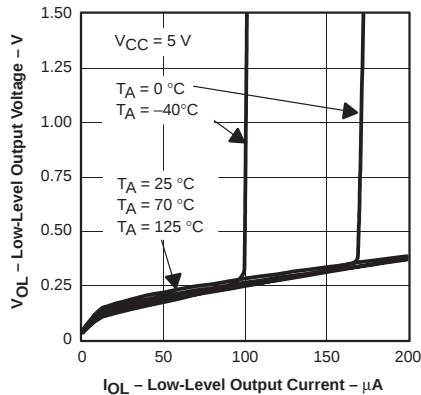


Figure 14

**HIGH-LEVEL OUTPUT VOLTAGE
VS
HIGH-LEVEL OUTPUT CURRENT**

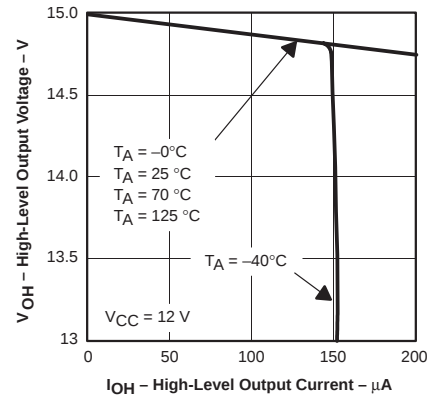


Figure 15

**LOW-LEVEL OUTPUT VOLTAGE
VS
LOW-LEVEL OUTPUT CURRENT**

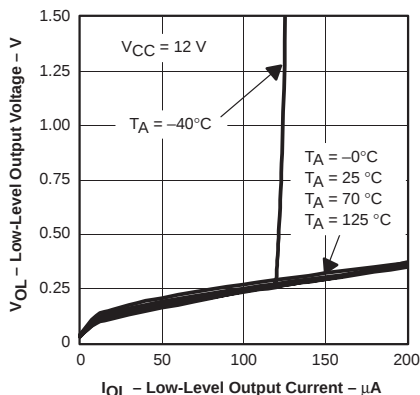


Figure 16

**OUTPUT VOLTAGE
PEAK-TO-PEAK
VS
FREQUENCY**

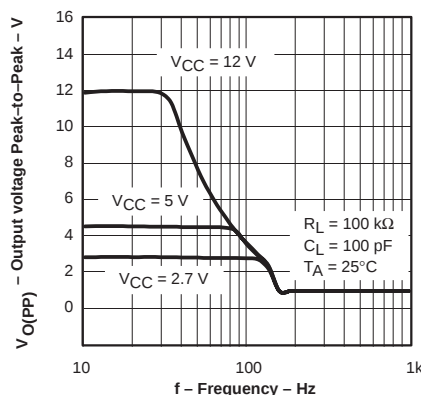


Figure 17

**OUTPUT IMPEDANCE
VS
FREQUENCY**

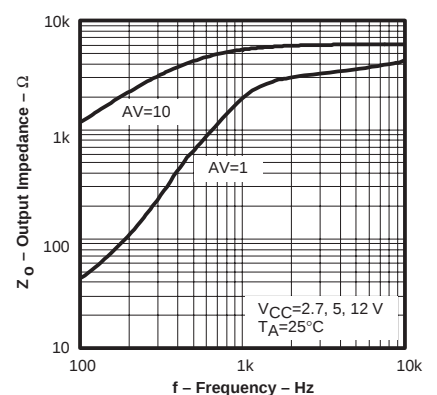


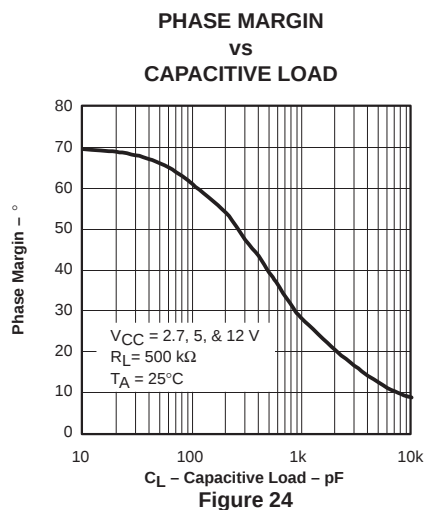
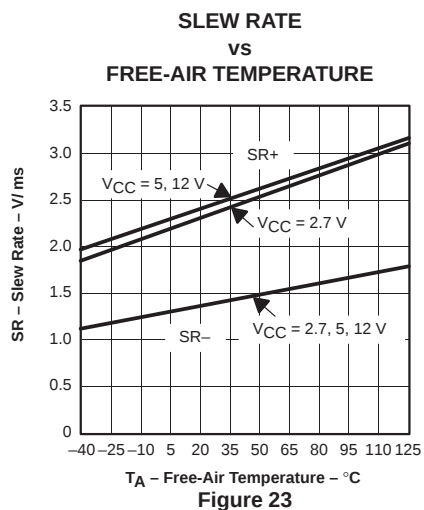
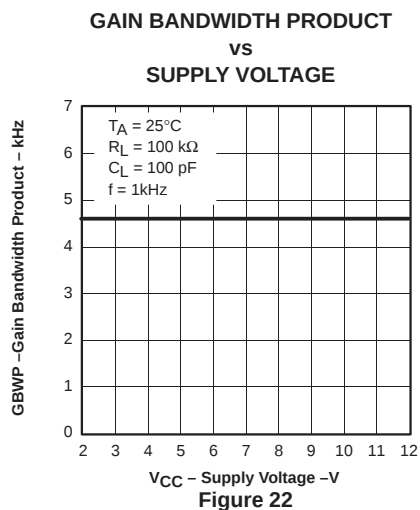
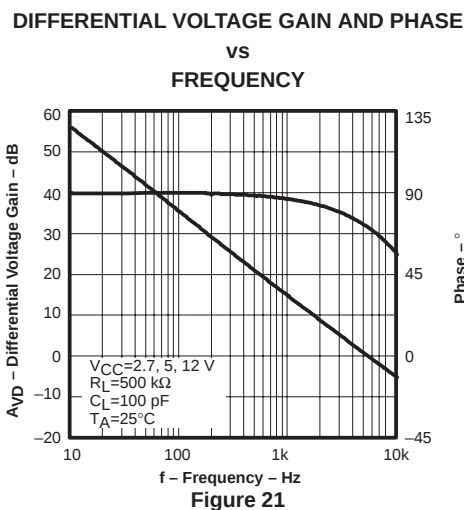
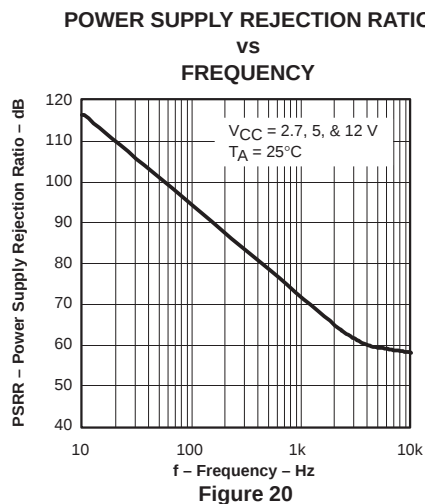
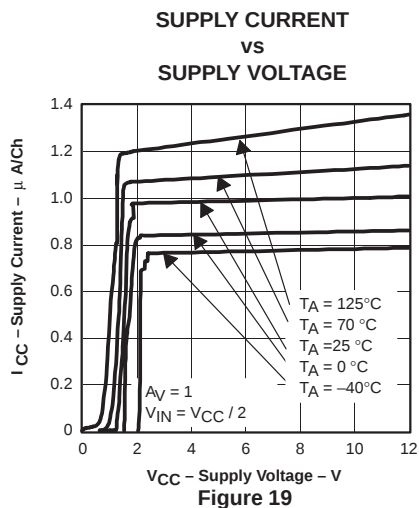
Figure 18

TLV2241, TLV2242, TLV2244

FAMILY OF 1- μ A/ch RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED - NOVEMBER 2000

TYPICAL CHARACTERISTICS



TLV2241, TLV2242, TLV2244

FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED – NOVEMBER 2000

TYPICAL CHARACTERISTICS

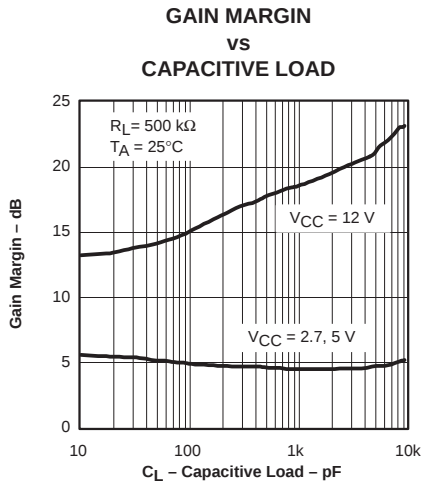


Figure 25

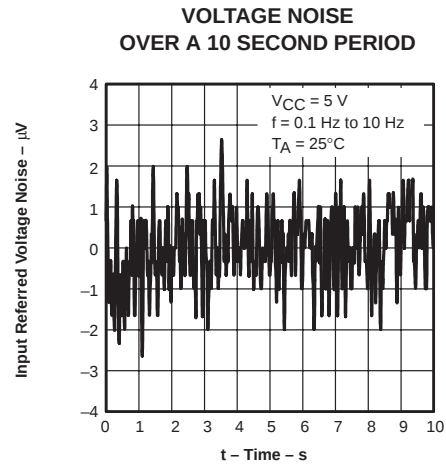


Figure 26

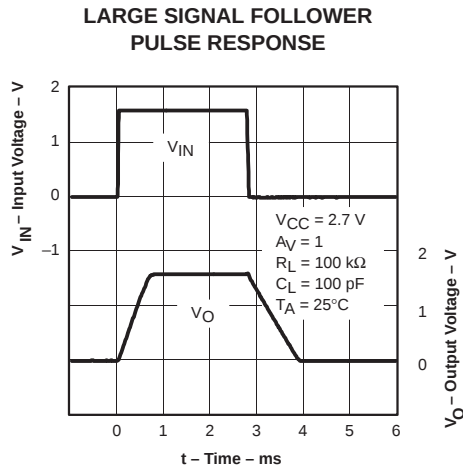


Figure 27

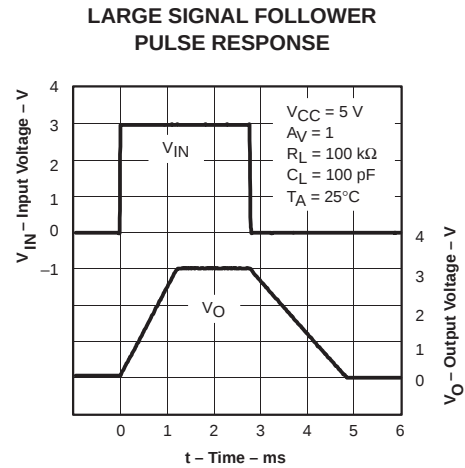


Figure 28

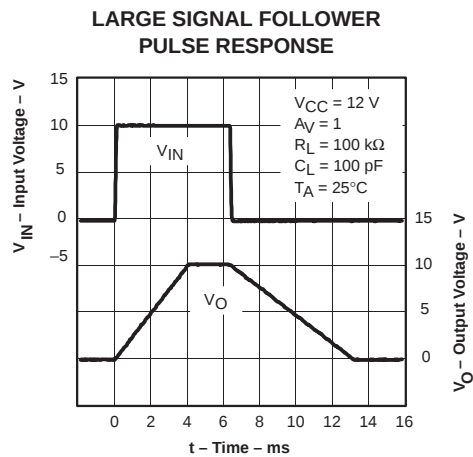


Figure 29

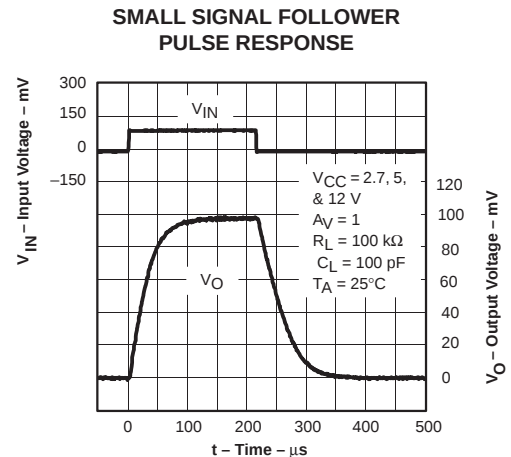


Figure 30

TLV2241, TLV2242, TLV2244

FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT

OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED – NOVEMBER 2000

TYPICAL CHARACTERISTICS

LARGE SIGNAL INVERTING PULSE RESPONSE

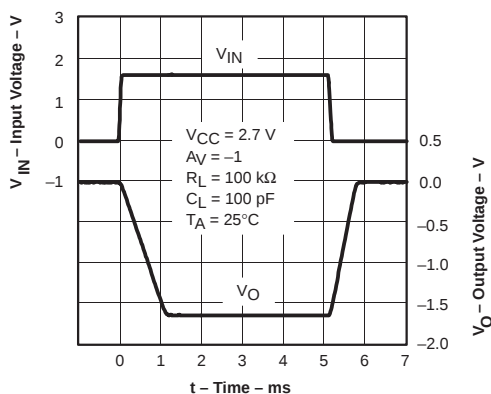


Figure 31

LARGE SIGNAL INVERTING PULSE RESPONSE

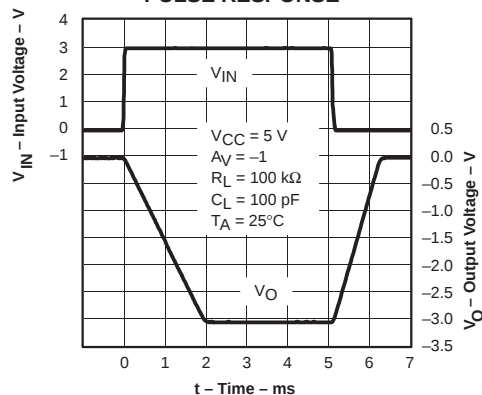


Figure 32

LARGE SIGNAL INVERTING PULSE RESPONSE

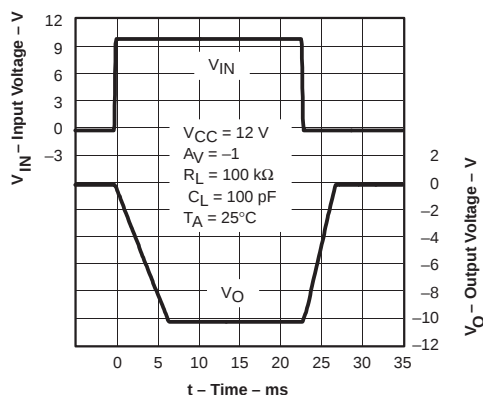


Figure 33

SMALL SIGNAL INVERTING PULSE RESPONSE

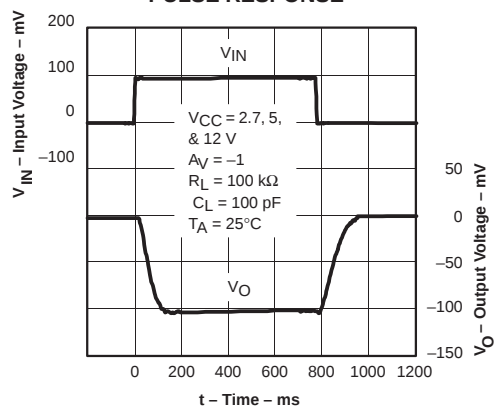


Figure 34

**CROSSTALK
vs
FREQUENCY**

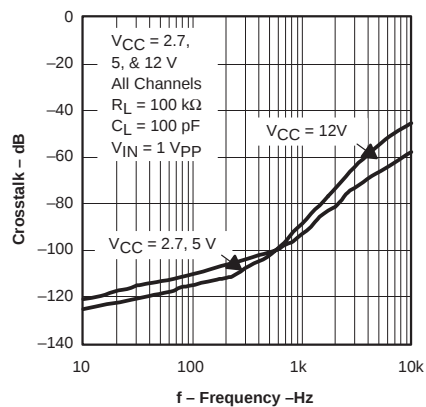
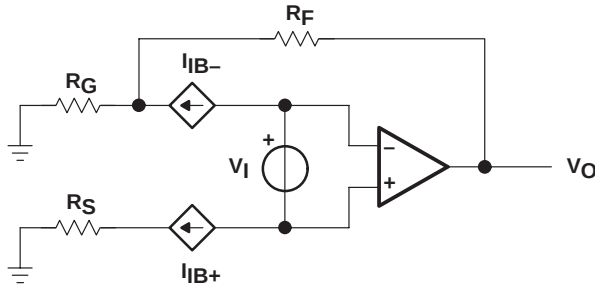


Figure 35

APPLICATION INFORMATION

offset voltage

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:

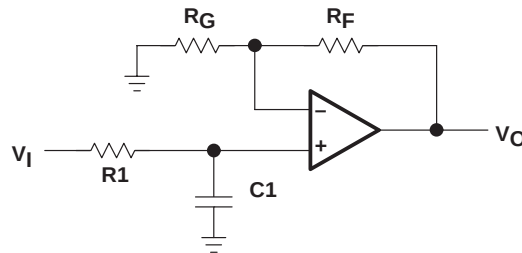


$$V_{OO} = V_{IO} \left(1 + \left(\frac{R_F}{R_G} \right) \right) \pm I_{IB+} R_S \left(1 + \left(\frac{R_F}{R_G} \right) \right) \pm I_{IB-} R_F$$

Figure 36. Output Offset Voltage Model

general configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 37).

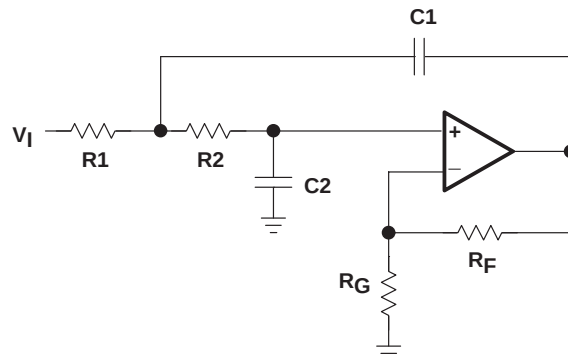


$$f_{-3dB} = \frac{1}{2\pi R_1 C_1}$$

$$\frac{V_O}{V_I} = \left(1 + \frac{R_F}{R_G} \right) \left(\frac{1}{1 + sR_1 C_1} \right)$$

Figure 37. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.



$$\begin{aligned} R_1 &= R_2 = R \\ C_1 &= C_2 = C \\ Q &= \text{Peaking Factor} \\ &(\text{Butterworth } Q = 0.707) \end{aligned}$$

$$f_{-3dB} = \frac{1}{2\pi RC}$$

$$R_G = \frac{R_F}{\left(2 - \frac{1}{Q} \right)}$$

Figure 38. 2-Pole Low-Pass Sallen-Key Filter

TLV2241, TLV2242, TLV2244

FAMILY OF 1- μ A/ch RAIL-TO-RAIL INPUT/OUTPUT

OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED - NOVEMBER 2000

APPLICATION INFORMATION

circuit layout considerations

To achieve the levels of high performance of the TLV224x, follow proper printed-circuit board design techniques. A general set of guidelines is given in the following.

- **Ground planes**—It is highly recommended that a ground plane be used on the board to provide all components with a low inductive ground connection. However, in the areas of the amplifier inputs and output, the ground plane can be removed to minimize the stray capacitance.
- **Proper power supply decoupling**—Use a 6.8- μ F tantalum capacitor in parallel with a 0.1- μ F ceramic capacitor on each supply terminal. It may be possible to share the tantalum among several amplifiers depending on the application, but a 0.1- μ F ceramic capacitor should always be used on the supply terminal of every amplifier. In addition, the 0.1- μ F capacitor should be placed as close as possible to the supply terminal. As this distance increases, the inductance in the connecting trace makes the capacitor less effective. The designer should strive for distances of less than 0.1 inches between the device power terminals and the ceramic capacitors.
- **Sockets**—Sockets can be used but are not recommended. The additional lead inductance in the socket pins will often lead to stability problems. Surface-mount packages soldered directly to the printed-circuit board is the best implementation.
- **Short trace runs/compact part placements**—Optimum high performance is achieved when stray series inductance has been minimized. To realize this, the circuit layout should be made as compact as possible, thereby minimizing the length of all trace runs. Particular attention should be paid to the inverting input of the amplifier. Its length should be kept as short as possible. This will help to minimize stray capacitance at the input of the amplifier.
- **Surface-mount passive components**—Using surface-mount passive components is recommended for high performance amplifier circuits for several reasons. First, because of the extremely low lead inductance of surface-mount components, the problem with stray series inductance is greatly reduced. Second, the small size of surface-mount components naturally leads to a more compact layout thereby minimizing both stray inductance and capacitance. If leaded components are used, it is recommended that the lead lengths be kept as short as possible.



APPLICATION INFORMATION

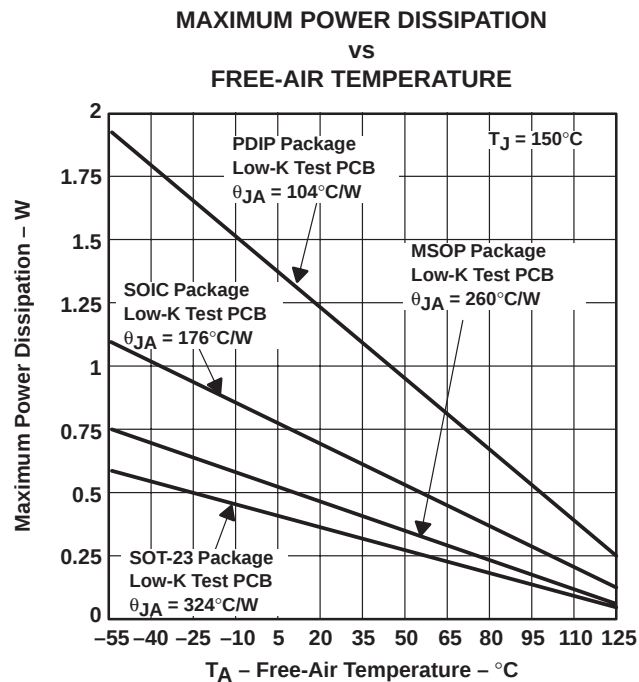
general power dissipation considerations

For a given θ_{JA} , the maximum power dissipation is shown in Figure 39 and is calculated by the following formula:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right)$$

Where:

- P_D = Maximum power dissipation of THS224x IC (watts)
- T_{MAX} = Absolute maximum junction temperature (150°C)
- T_A = Free-ambient air temperature (°C)
- $\theta_{JA} = \theta_{JC} + \theta_{CA}$
- θ_{JC} = Thermal coefficient from junction to case
- θ_{CA} = Thermal coefficient from case to ambient air (°C/W)



NOTE A: Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 39. Maximum Power Dissipation vs Free-Air Temperature

TLV2241, TLV2242, TLV2244

FAMILY OF 1- μ A/Ch RAIL-TO-RAIL INPUT/OUTPUT

OPERATIONAL AMPLIFIERS

SLOS329C – JULY 2000 REVISED - NOVEMBER 2000

APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*™ Release 8, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 2) and subcircuit in Figure 40 are generated using the TLV224x typical electrical and operating characteristics at $T_A = 25^\circ\text{C}$. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 2: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers", *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

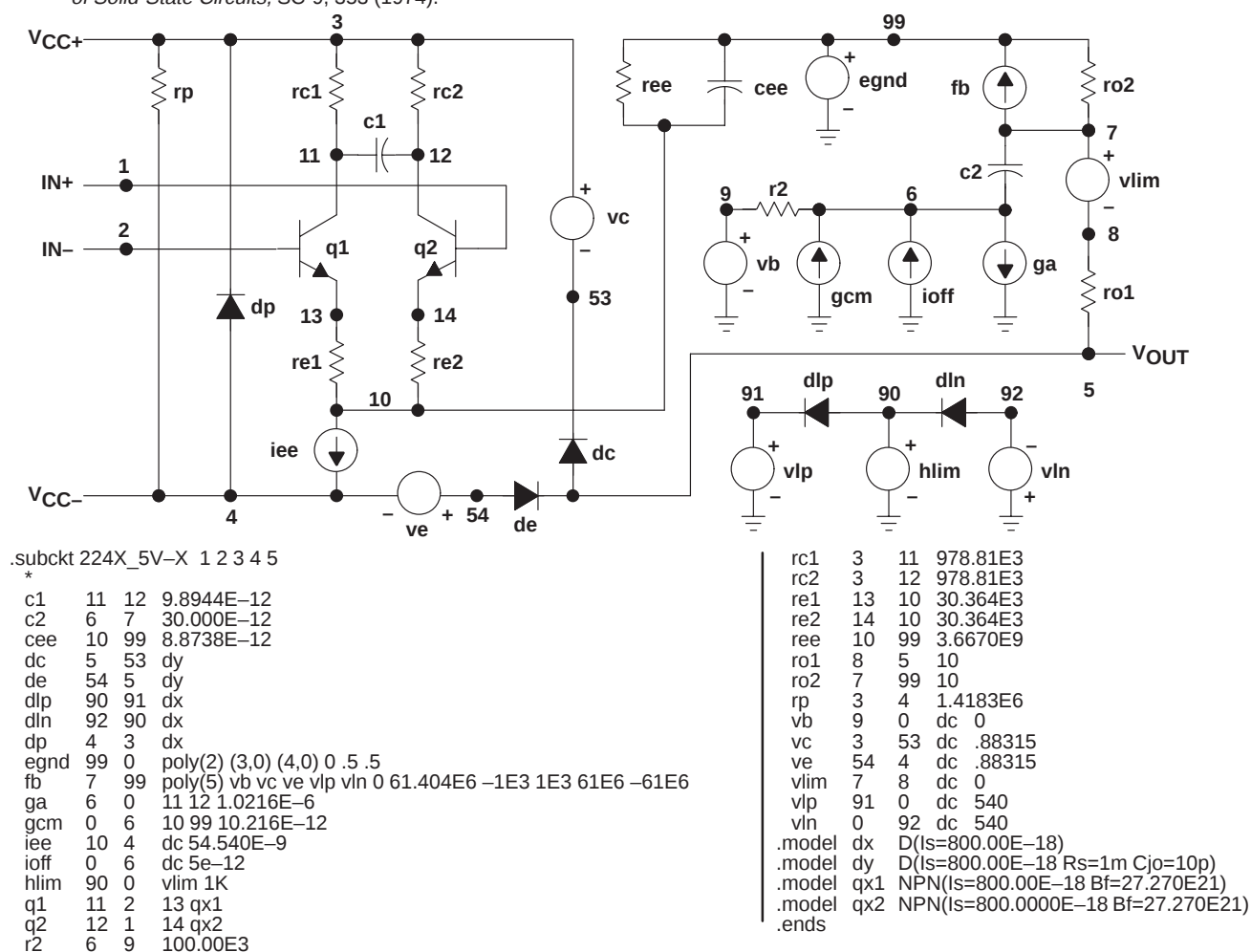


Figure 40. Boyle Macromodels and Subcircuit

PSpice and *Parts* are trademarks of MicroSim Corporation.



POST OFFICE BOX 655303 • DALLAS, TEXAS 75265

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV2241ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2241I	Samples
TLV2241IDBVR	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBEI	Samples
TLV2241IDBVRG4	ACTIVE	SOT-23	DBV	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBEI	Samples
TLV2241IDBVT	ACTIVE	SOT-23	DBV	5	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	VBEI	Samples
TLV2241IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2241I	Samples
TLV2241IP	ACTIVE	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	TLV2241I	Samples
TLV2242CD	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	2242C	Samples
TLV2242CDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	2242C	Samples
TLV2242ID	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2242I	Samples
TLV2242IDGK	ACTIVE	VSSOP	DGK	8	80	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ALE	Samples
TLV2242IDGKR	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ALE	Samples
TLV2242IDGKRG4	ACTIVE	VSSOP	DGK	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ALE	Samples
TLV2242IDR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2242I	Samples
TLV2242IP	ACTIVE	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	TLV2242I	Samples
TLV2244ID	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2244I	Samples
TLV2244IDR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2244I	Samples
TLV2244IN	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	TLV2244I	Samples
TLV2244IPW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2244I	Samples
TLV2244IPWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2244I	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of ≤ 1000 ppm threshold. Antimony trioxide based flame retardants must also meet the ≤ 1000 ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2241IDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2241IDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2241IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2242CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2242IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2242IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2244IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2244IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

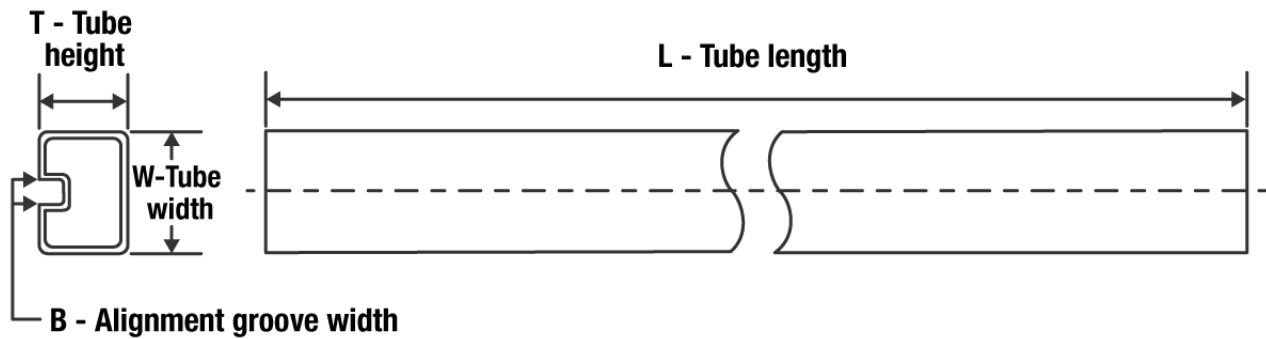
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2241IDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TLV2241IDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TLV2241IDR	SOIC	D	8	2500	340.5	336.1	25.0
TLV2242CDR	SOIC	D	8	2500	340.5	336.1	25.0
TLV2242IDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TLV2242IDR	SOIC	D	8	2500	340.5	336.1	25.0
TLV2244IDR	SOIC	D	14	2500	350.0	350.0	43.0
TLV2244IPWR	TSSOP	PW	14	2000	853.0	449.0	35.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLV2241ID	D	SOIC	8	75	507	8	3940	4.32
TLV2241ID	D	SOIC	8	75	505.46	6.76	3810	4
TLV2241IP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2242CD	D	SOIC	8	75	505.46	6.76	3810	4
TLV2242CD	D	SOIC	8	75	507	8	3940	4.32
TLV2242ID	D	SOIC	8	75	507	8	3940	4.32
TLV2242ID	D	SOIC	8	75	505.46	6.76	3810	4
TLV2242IP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2244ID	D	SOIC	14	50	505.46	6.76	3810	4
TLV2244IN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2244IPW	PW	TSSOP	14	90	530	10.2	3600	3.5

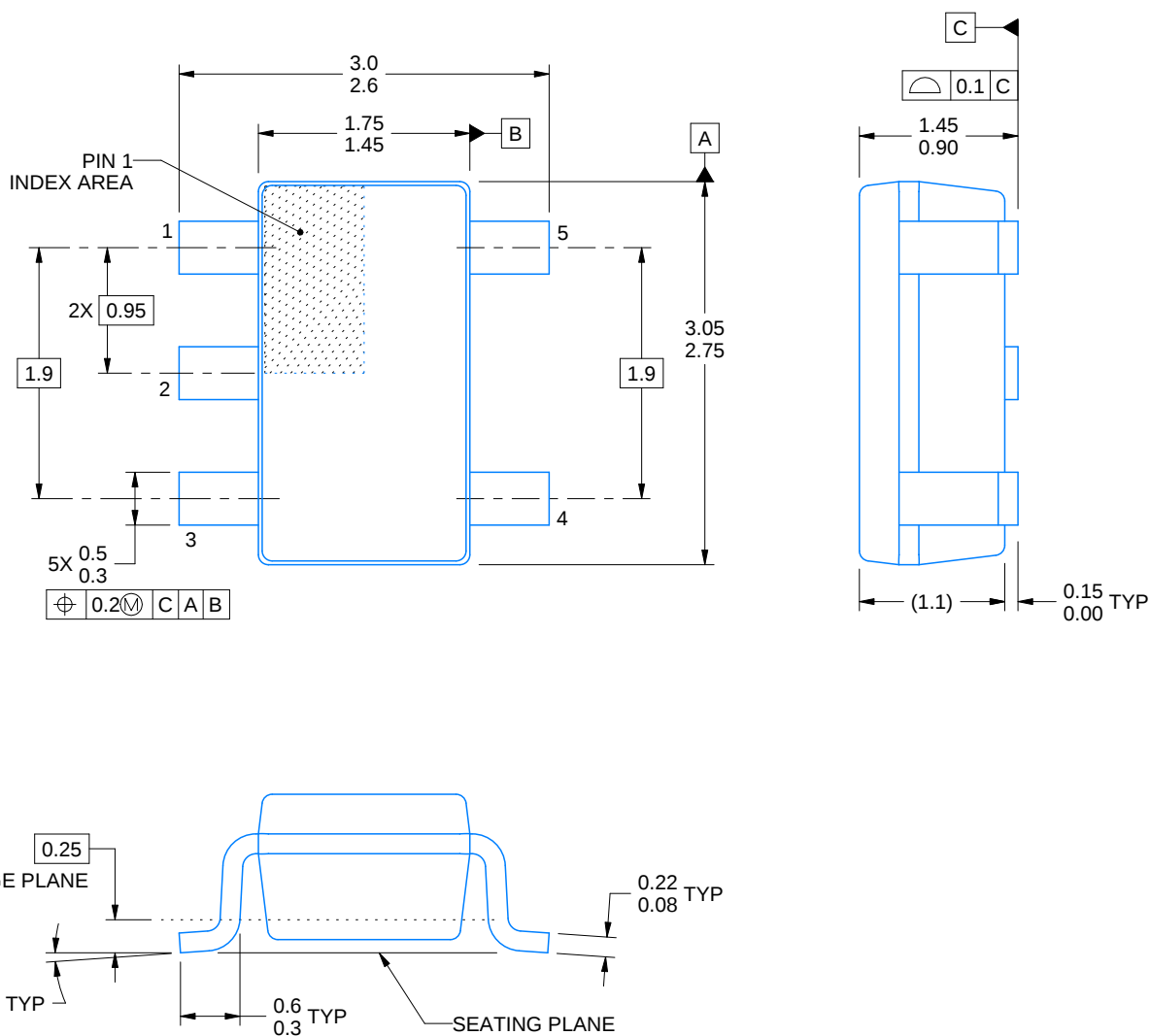


DBV0005A

PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



4214839/F 06/2021

NOTES:

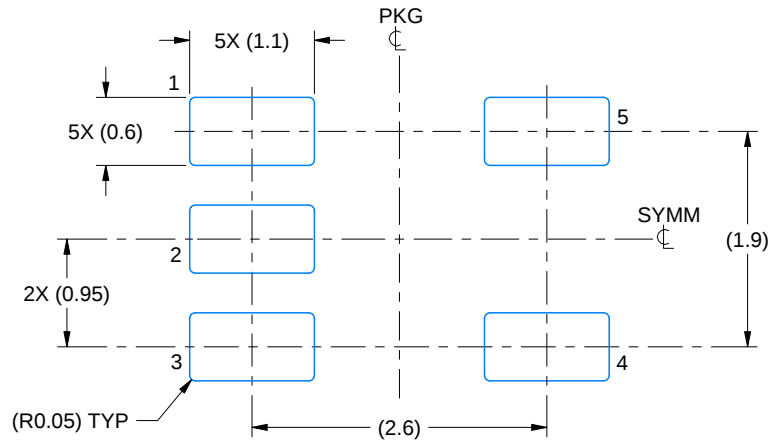
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.

EXAMPLE BOARD LAYOUT

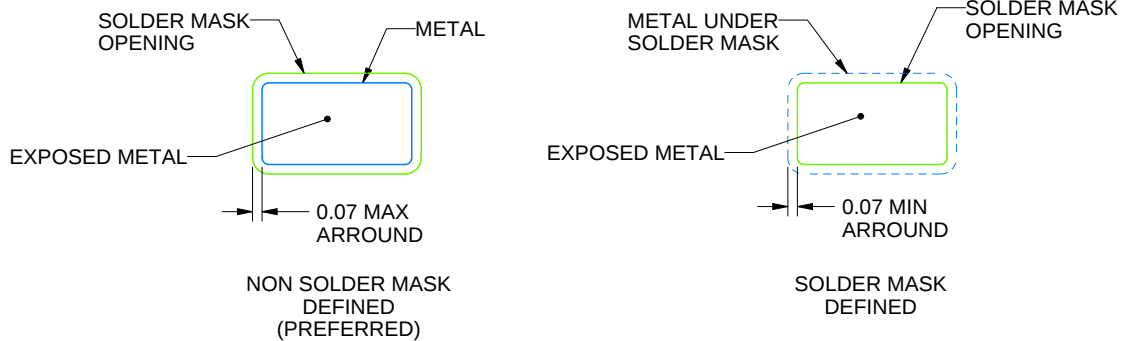
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/F 06/2021

NOTES: (continued)

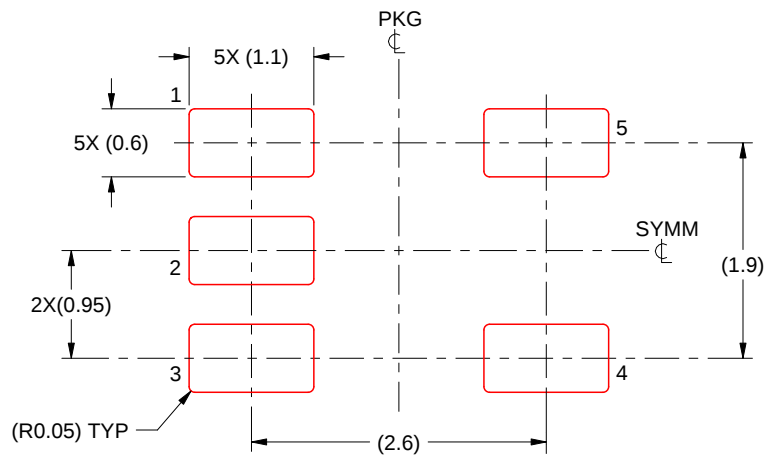
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/F 06/2021

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



4040047-5/M 06/11

NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.

D (R-PDSO-G14)

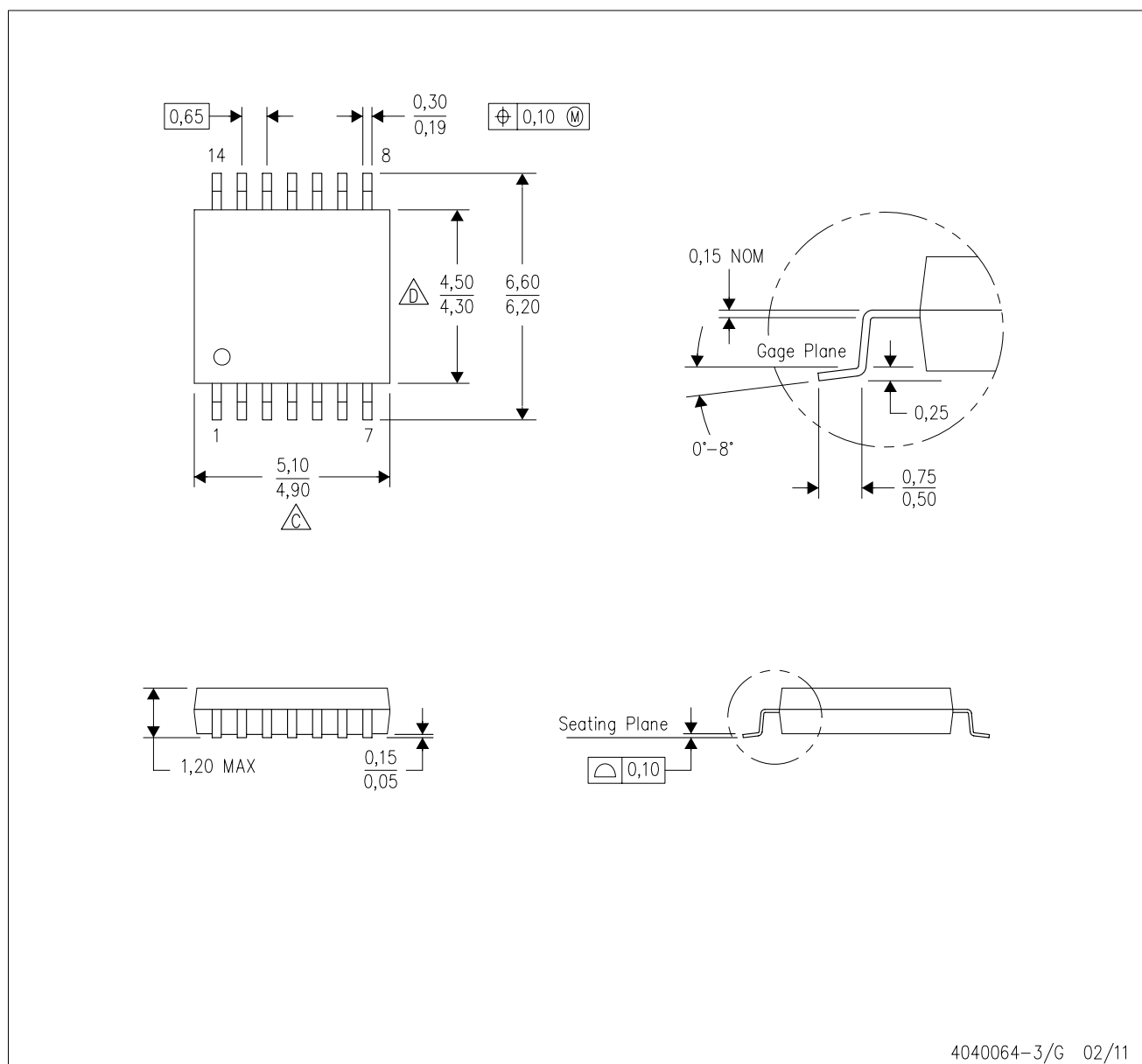
PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



4040064-3/G 02/11

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



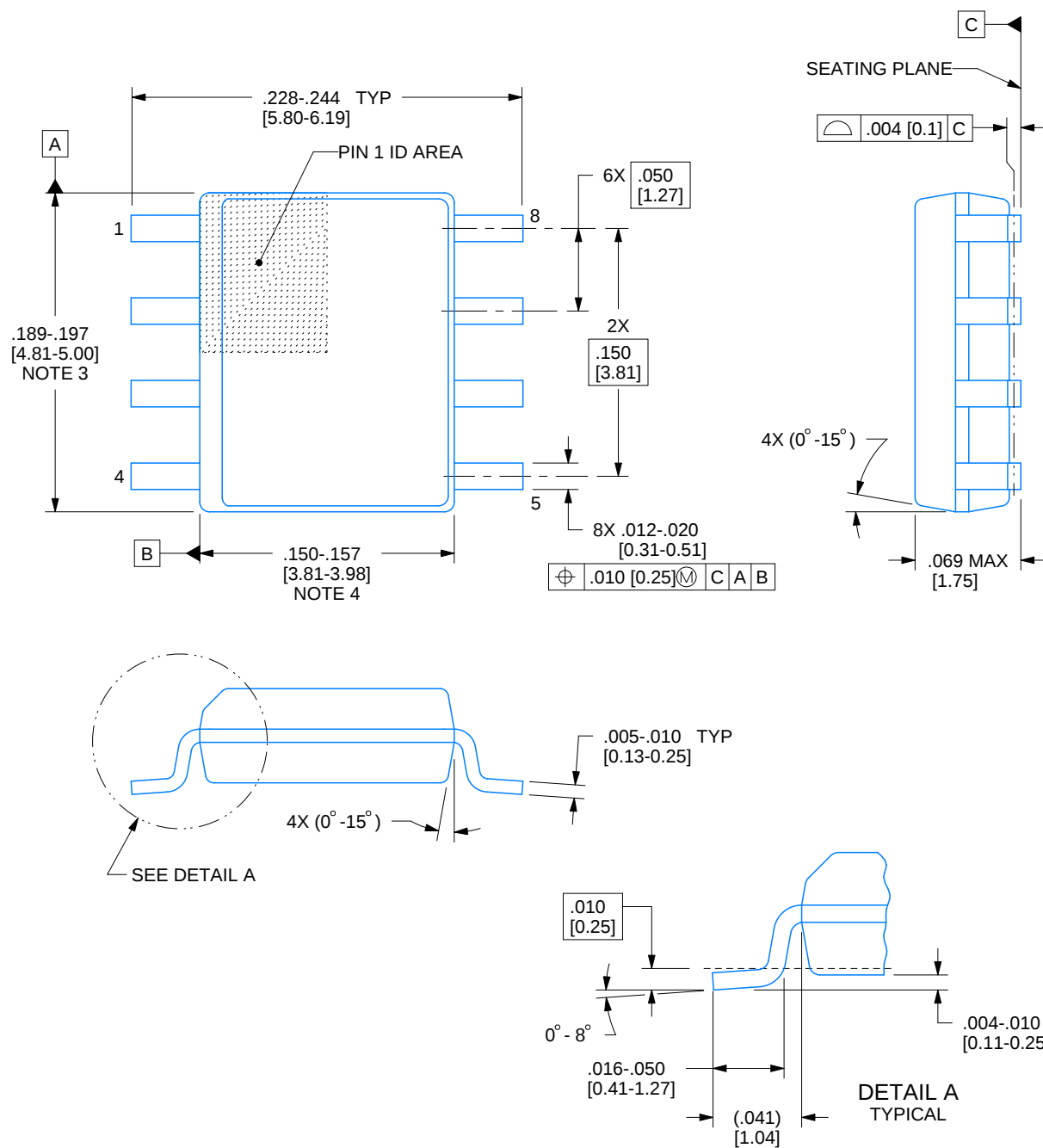
- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

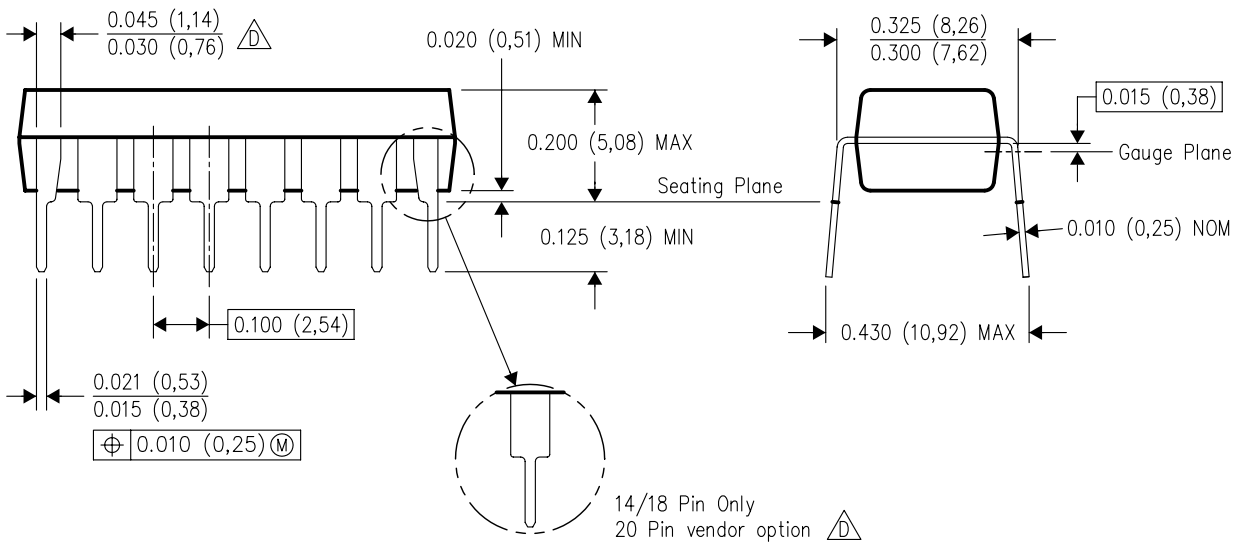
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS **	14	16	18	20
DIM				
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 - D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



4073329/E 05/06

NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.

DGK (S-PDSO-G8)

PLASTIC SMALL OUTLINE PACKAGE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](#) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2022, Texas Instruments Incorporated